

Vishay General Semiconductor

Surface Mount Ultrafast Plastic Rectifiers



DO-214AC (SMA)

FEATURES

- Low profile package
- Ideal for automated placement
- Glass passivated chip junction
- Ultrafast recovery times for high efficiency
- Low forward voltage, low power loss
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in secondary rectification and freewheeling for ultrafast switching speeds ac-to-ac and dc-to-dc converters in high temperature conditions for both consumer and automotive applications.

MECHANICAL DATA

Case: DO-214AC (SMA)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	ESH1B	ESH1C	ESH1D	UNIT	
Device marking code		EHB	EHC	EHD		
Maximum repetitive peak reverse voltage V _{RRM} 100 150 200				200	V	
Maximum RMS voltage	V _{RMS}	70	105	140	V	
Maximum DC blocking voltage	V _{DC}	100	150	200	V	
Maximum average forward rectified current at T_L = 150 °C	I _{F(AV)}	1.0			А	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	50			А	
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 175			°C	

PRIMARY CHARACTERISTICS					
I _{F(AV)} 1 A					
V _{RRM} 100 V, 150 V, 200 V					
t _{rr}	25 ns				
V _F	0.90 V				
T _J max.	175 °C				



RoHS

COMPLIANT

ESH1B, ESH1C & ESH1D

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT	
Maximum instantaneous forward voltage	I _F = 0.7 A ⁽¹⁾ I _F = 1 A		V _F	0.87 0.90	V	
Maximum DC reverse current at rated DC blocking voltage		T _A = 25 °C T _A = 125 °C	I _R	1.0 25	μΑ	
Maximum reverse current	V _R = 20 V, T _J = 150 °C	•	I _R	50	μA	
Maximum reverse recovery time	$I_{\rm F} = 0.5 \text{ A}, I_{\rm R} = 1 \text{ A}, I_{\rm rr} = 0.25 \text{ A}$		t _{rr}	25	ns	
Typical reverse recovery time	$I_F = 0.6 \text{ A}, V_R = 30 \text{ V},$ dI/dt = 50 A/µs, $I_{rr} = 10 \% I_{RM}$	T _J = 25 °C T _J = 100 °C	t _{rr}	25 35	ns	
Typical stored charge	$I_F = 0.6 \text{ A}, V_R = 30 \text{ V},$ dI/dt = 50 A/ μ s, $I_{rr} = 10 \% I_{RM}$	T _J = 25 °C T _J = 100 °C	Q _{rr}	10 15	nC	
Typical junction capacitance	4.0 V, 1 MHz		CJ	25	pF	

Note:

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	OL ESH1B ESH1C ESH1D		UNIT		
Typical thermal resistance ⁽¹⁾	${\sf R}_{ heta {\sf J} {\sf A}} \ {\sf R}_{ heta {\sf J} {\sf L}}$	85 30		°C/W		

Note:

(1) Units mounted on P.C.B. with 5.0 x 5.0 mm (0.013 mm thick) land areas

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
ESH1D-E3/61T	0.064	61T	1800	7" diameter plastic tape and reel	
ESH1D-E3/5AT	0.064	5AT	7500	13" diameter plastic tape and reel	
ESH1DHE3/61T (1)	0.064	61T	1800	7" diameter plastic tape and reel	
ESH1DHE3/5AT ⁽¹⁾	0.064	5AT	7500	13" diameter plastic tape and reel	

Note:

(1) Automotive grade AEC Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

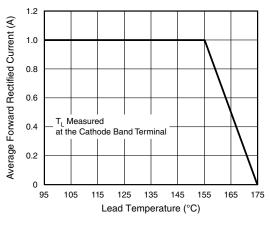


Figure 1. Maximum Forward Current Derating Curve

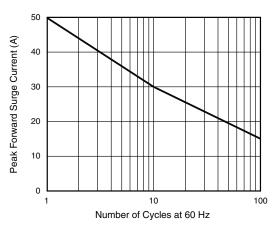


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



ESH1B, ESH1C & ESH1D

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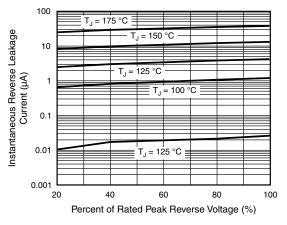


Figure 3. Typical Reverse Leakage Characteristics

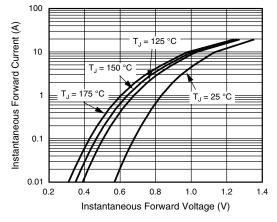


Figure 4. Typical Instantaneous Forward Characteristics



DO-214AC (SMA)

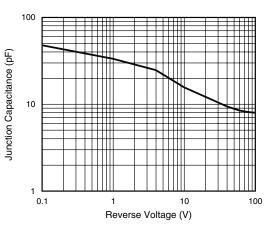


Figure 5. Typical Junction Capacitance

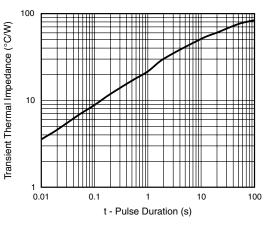
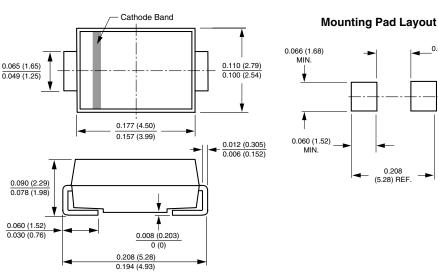


Figure 6. Typical Transient Thermal Impedance

0.074 (1.88)

MAX.



For technical questions within your region, please contact one of the following: PDD-Americas@vishay.com, PDD-Asia@vishay.com, PDD-Europe@vishay.com



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